

MOS FIELD EFFECT TRANSISTOR NP160N04TUG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP160N04TUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP160N04TUG-E1-AY ^{Note}	Pure Sn (Tin)	Tape 800 p/reel	TO-263-7pin (MP-25ZT) typ. 1.5 g
NP160N04TUG-E2-AY ^{Note}			

Note Pb-free (This product does not contain Pb in the external electrode).

FEATURES

- Super low on-state resistance
 $R_{DS(on)} = 1.6 \text{ m}\Omega \text{ TYP.} / 2.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 10 \text{ V}$, $I_D = 80 \text{ A}$)
- High Current Rating
 $I_{D(DC)} = \pm 160 \text{ A}$

(TO-263-7pin)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	40	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 160	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	± 640	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	220	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2}	1.8	W
Channel Temperature	T_{ch}	175	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +175	$^\circ\text{C}$
Single Avalanche Energy ^{Note2}	E_{AS}	372	mJ
Repetitive Avalanche Current ^{Note3}	I_{AR}	61	A
Repetitive Avalanche Energy ^{Note3}	E_{AR}	372	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 20 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$, $L = 100 \mu\text{H}$

3. $R_G = 25 \Omega$, $T_{ch(peak)} \leq 150^\circ\text{C}$

THERMAL RESISTANCE

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	0.68	$^\circ\text{C/W}$
Channel to Ambient Thermal Resistance	$R_{th(ch-A)}$	83.3	$^\circ\text{C/W}$

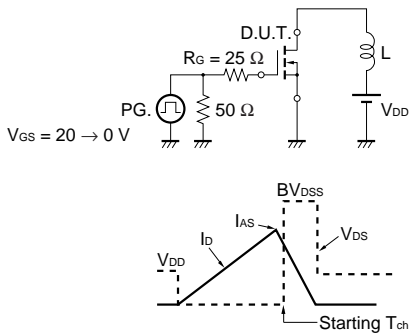
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

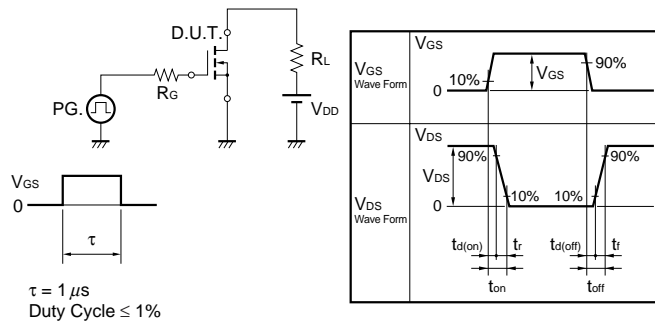
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			1	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 5 V, I _D = 40 A	28	76		S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)}	V _{GS} = 10 V, I _D = 80 A		1.6	2.0	mΩ
Input Capacitance	C _{iss}	V _{DS} = 25 V,		10500	15750	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V,		980	1470	pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		630	1140	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 20 V, I _D = 80 A,		47	110	ns
Rise Time	t _r	V _{GS} = 10 V,		67	170	ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		94	190	ns
Fall Time	t _f			19	50	ns
Total Gate Charge ^{Note}	Q _G	V _{DD} = 32 V,		178	270	nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V,		44		nC
Gate to Drain Charge	Q _{GD}	I _D = 160 A		61		nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 160 A, V _{GS} = 0 V		0.92	1.5	V
Reverse Recovery Time	t _{rr}	I _F = 160 A, V _{GS} = 0 V,		50		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		75		nC

Note Pulsed test

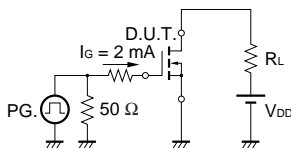
TEST CIRCUIT 1 AVALANCHE CAPABILITY



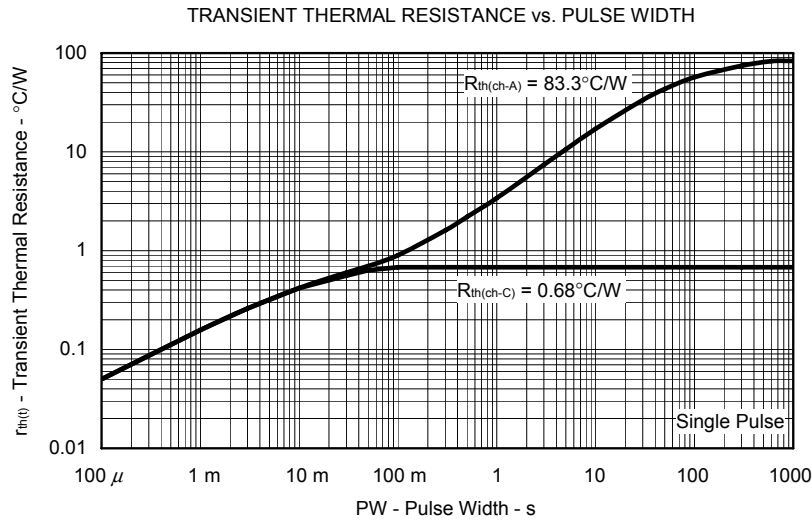
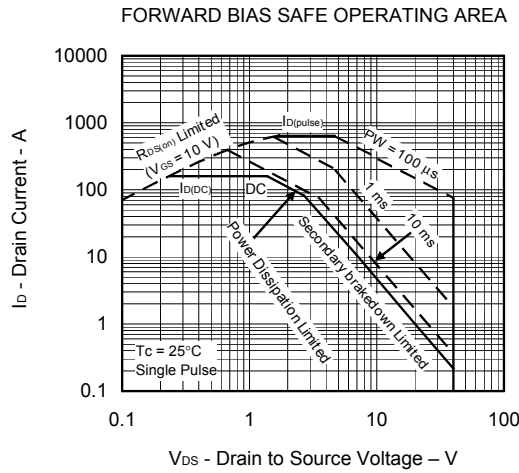
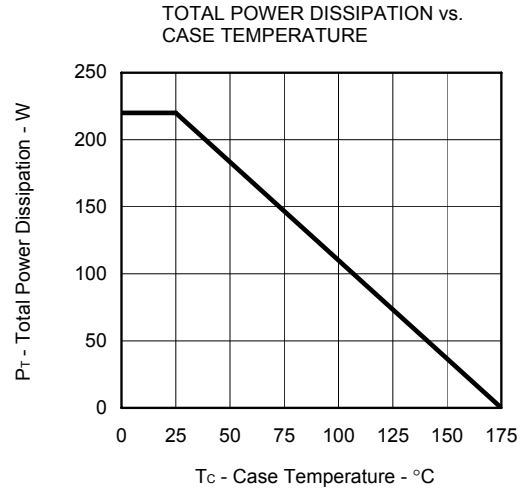
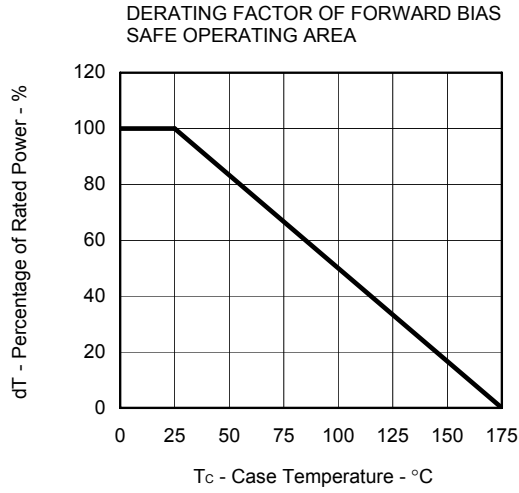
TEST CIRCUIT 2 SWITCHING TIME



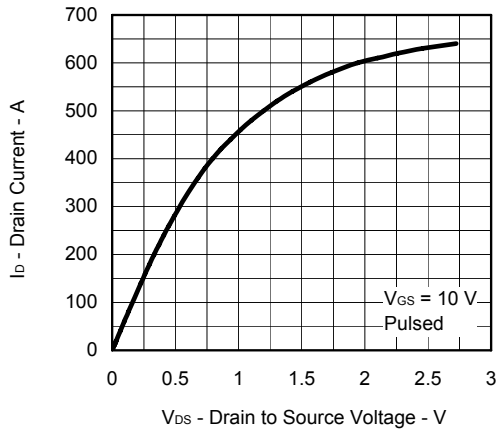
TEST CIRCUIT 3 GATE CHARGE



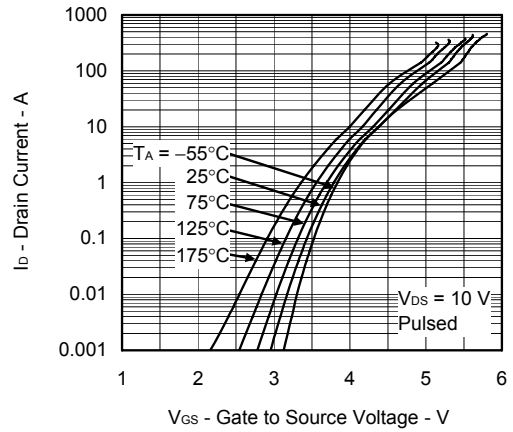
TYPICAL CHARACTERISTICS (T_A = 25°C)



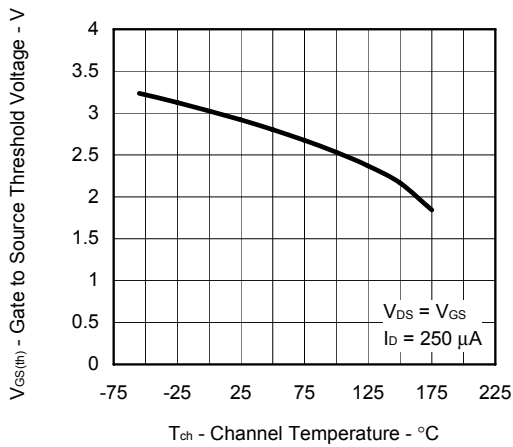
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



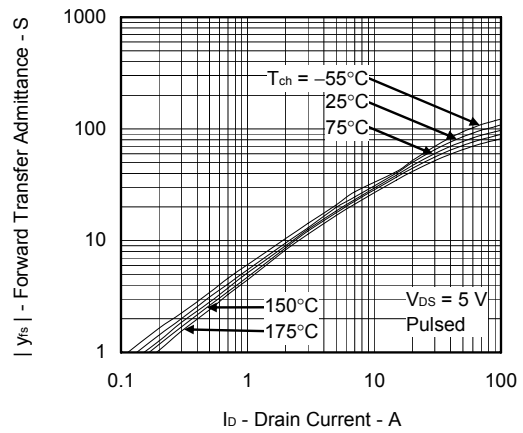
FORWARD TRANSFER CHARACTERISTICS



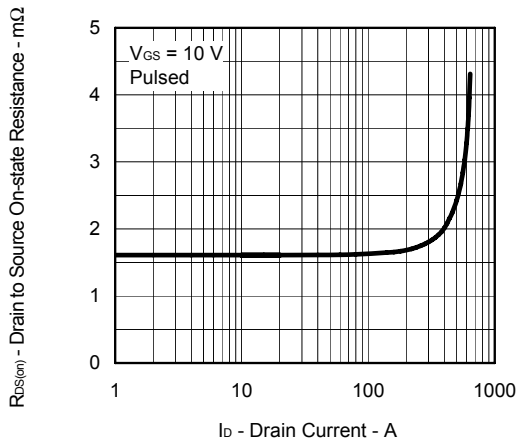
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



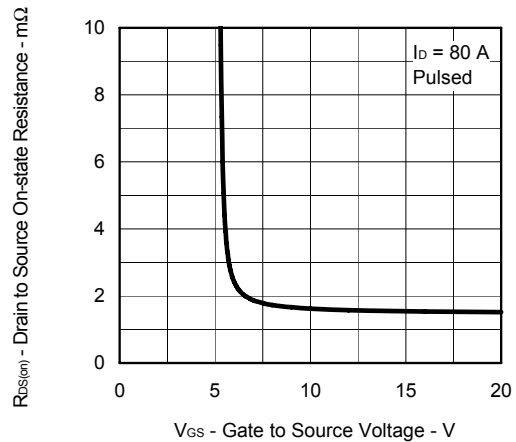
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

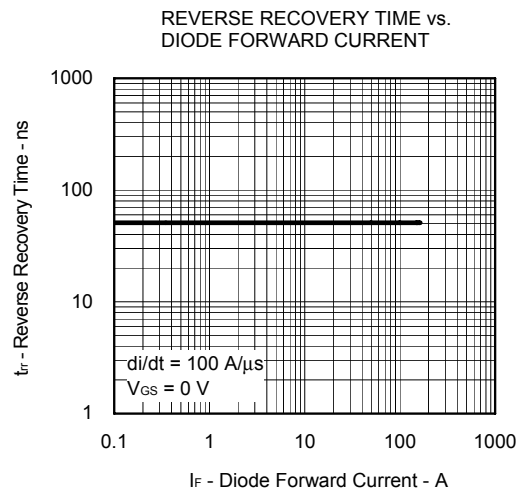
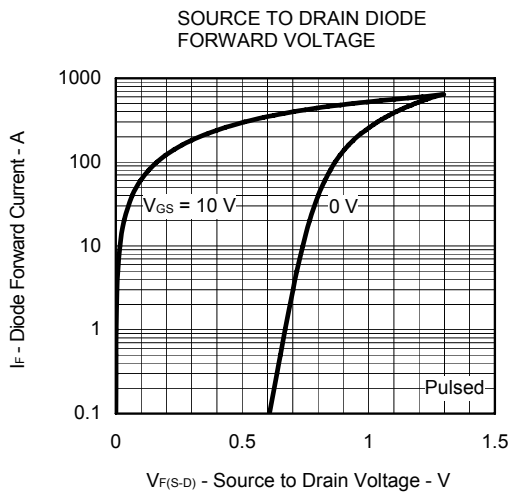
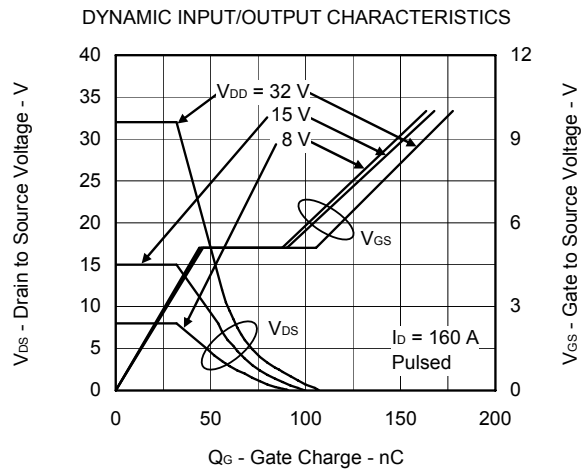
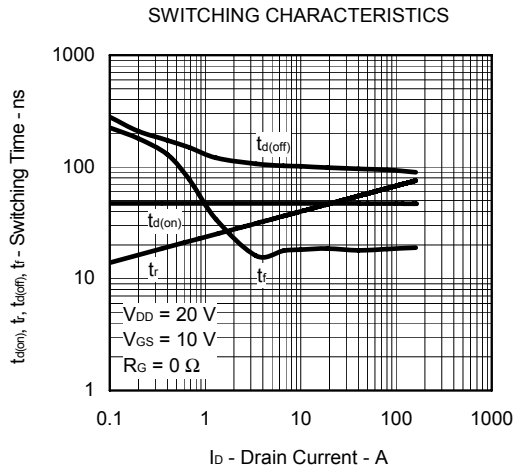
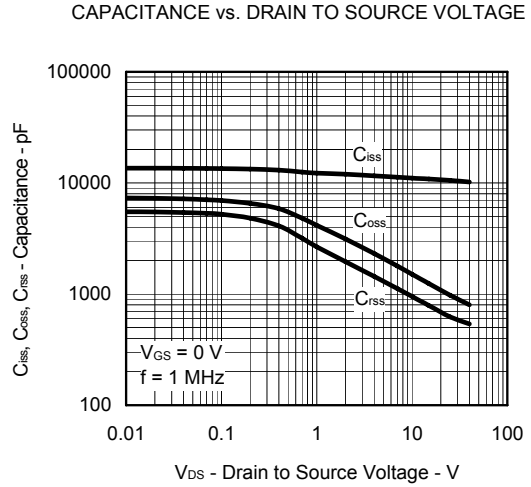
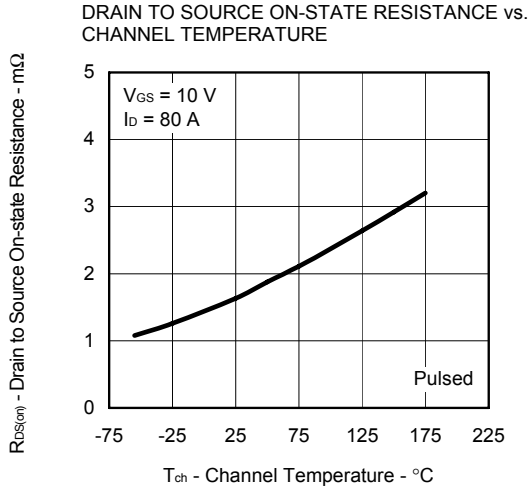


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



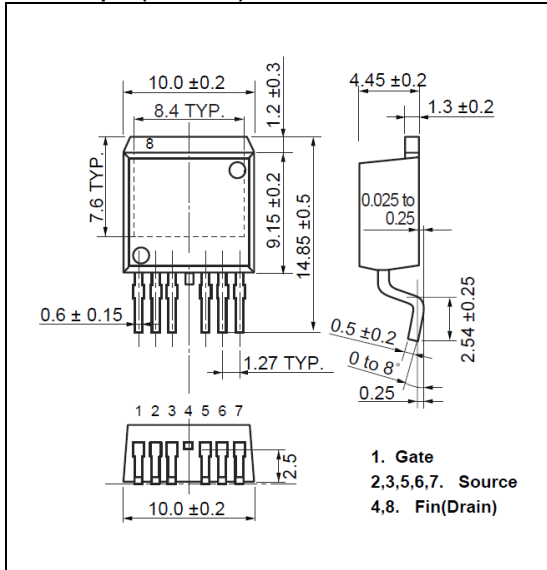
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



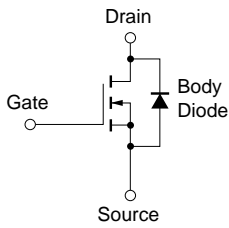


PACKAGE DRAWING (Unit: mm)

TO-263-7pin (MP-25ZT)



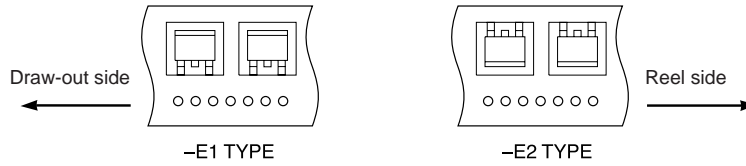
EQUIVALENT CIRCUIT



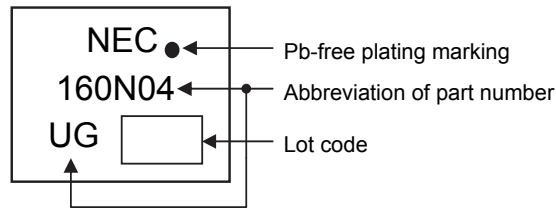
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP160N04TUG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	IR60-00-3
Partial heating	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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